



RSM

www.raystar-tek.com

XO5052Cx/Bx-Q

Fundamental Crystal Oscillator IC

Features

- Wide range of operating voltage: 1.6V to 5.5V
- Low crystal drive current oscillation for miniature crystal units
- XO5052C/B-Q series: for Wire Bonding
 - XO5052Cx-Q : C type package
 - XO5052Bx-Q: B type package(2016)
- -45 to 125°C operating temperature range
- Crystal frequency (10MHz~60MHz)
- Output Freq: Crystal Freq divided by 1/2/4/8/16
- Very low standby current
- 50±5% output duty cycle
- 50pF output drive capability (2.25~5.5V)
- 15pF output drive capability (1.6~5.5V)
- Die form or Wafer form
- AEC-Q 100 qualified. PPAP capable, and manufactured in IATF 16949 certified facilities.

Applications

- Fundamental Crystal Oscillator
- 7050, 5032, 3225, 2520, 2016 (XO5052C/B1-4) crystal oscillator

Description

The XO5052xy-Q series are miniature crystal oscillator module ICs. The oscillator circuit stage has constant current drive, significantly reducing current consumption and crystal current, compared with existing devices, and significantly reducing the oscillator characteristics supply voltage dependency.

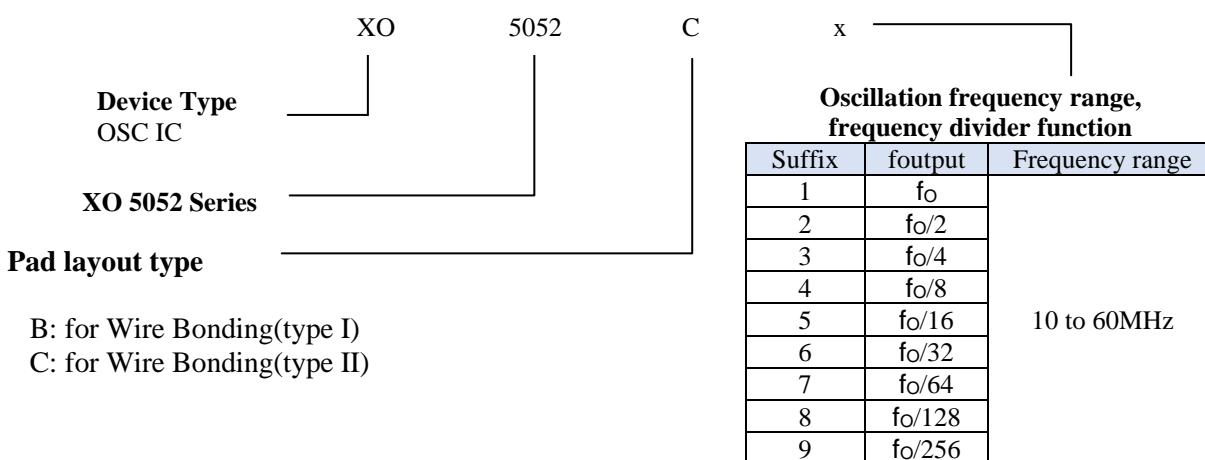
Ordering Information

Part no.	Package type
XO5052xy-zWF-Q	Wafer form
XO5052xy-zDE-Q	Die form

Note 1: x: B suitable for B Base, C suitable for C base

Note 2: y: 1/2/3/4(1//2/4/8/16)

Note 3: z: -8(180um) or -3(130um), -4(100um)



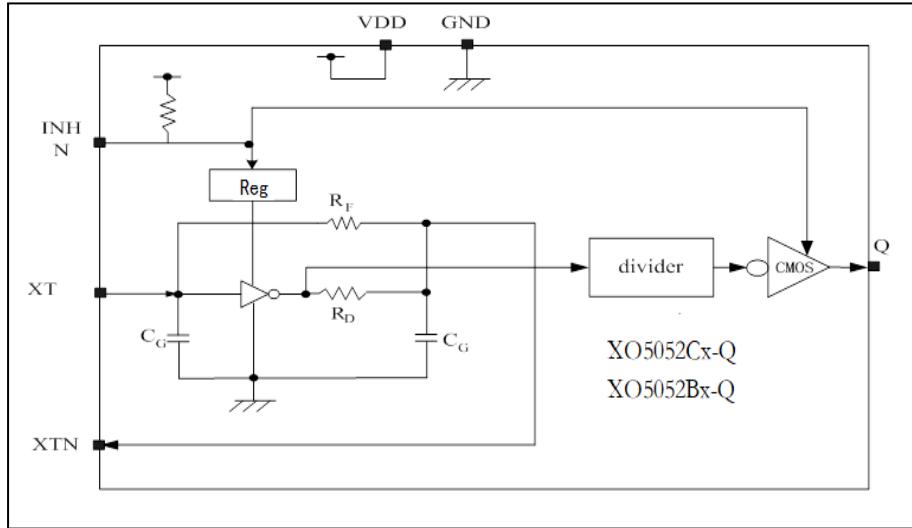


RSM

www.raystar-tek.com

XO5052Cx/Bx-Q
Fundamental Crystal Oscillator IC

Block Diagram



Function Description

Standby Function

When INHN goes LOW, the oscillator stops and the output on Q becomes high impedance.

INHN	Q	Oscillator
HIGH (or open)	F0/1/2/4/8/16 output frequency	Normal operation
Low	High impedance	Stopped

Power-saving Pull-up Resistor

The INHN pin pull-up resistance RUP1 or RUP2 changes in response to the input level(HIGH or LOW). When INHN is tied LOW level, the pull-up resistance is large(RUP1),reducing the current consumed by the resistance. When INHN is left open circuit, the pull-up resistance is small(RUP2),which increases the input susceptibility to external noise. However, the pull-up resistance ties the INHN pin HIGH level to prevent external noise from unexpectedly stopping the output.



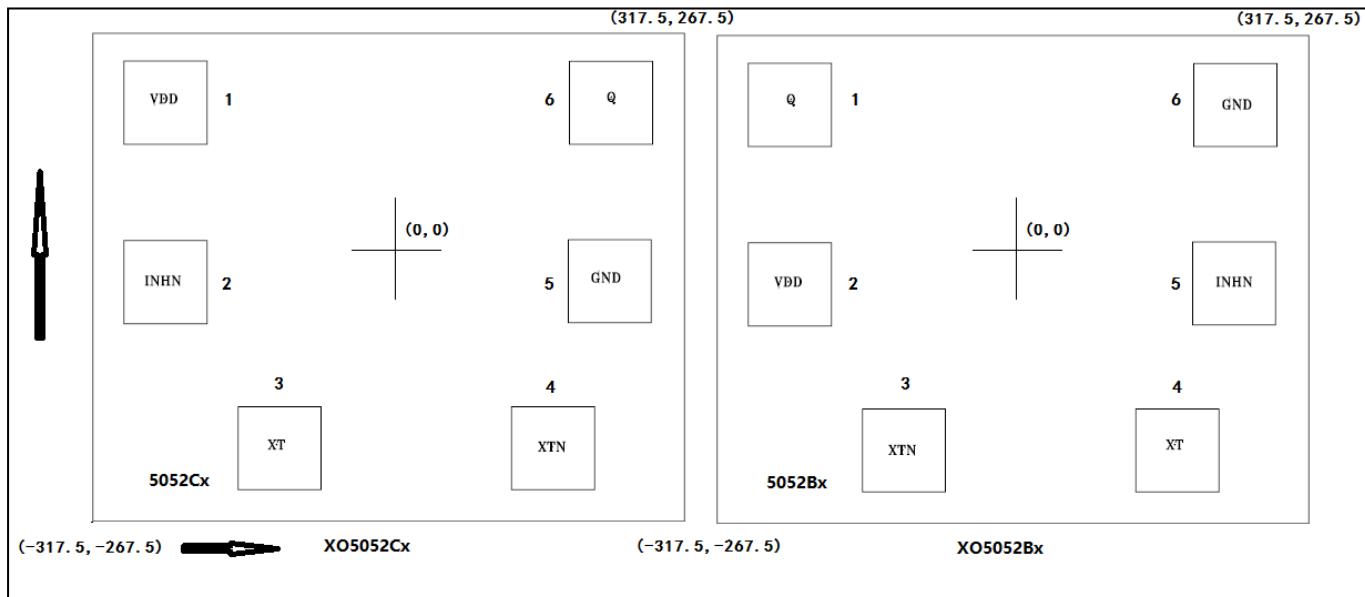
RSM

www.raystar-tek.com

XO5052Cx/Bx-Q

Fundamental Crystal Oscillator IC

Pad Configuration



Pad Coordinate File					
Pad Name	X Coordinate	Y Coordinate	Pad Name	X Coordinate	Y Coordinate
1	-214.85	168	4	158.35	-164.6
2	-214.85	-4.65	5	213.15	-3.85
3	-105.1	-164.6	6	214.2	167.9

Note: Substrate is connected to GND or floating.

Die Size: 630μm*530μm (Including scribe line , Scribe Line Width 60um)

Die Thickness: 130μm±15μm(-3) or 180um±20um(-8), 220um±20um(-2), 100um±15um(-4)

Pad Size: 80μm*80μm **Substrate Level:** GND or Floating

Pin Description

Sym.	Type	Description	
XTN	O	Amplifier output.	Crystal oscillator connected between XT and XTN
XT	I	Amplifier input.	
INHN	I	Output state control input. Output High when LOW. Power-saving pull-up resistor built in.	
V _{DD}	P	Supply voltage	
GND	P	Ground	
Q	O	Output. Output frequency determined by fundamental crystal(f0 divided by 1/2/4/8/16/..)	



RSM

www.raystar-tek.com

XO5052Cx/Bx-Q
Fundamental Crystal Oscillator IC

Maximum Ratings

Storage Temperature	- 65°C to +150°C
Supply Voltage to Ground Potential (V_{DD} to GND)	-0.5V to +7.0V
DC Input (All Other Inputs except V_{DD} & GND)-	-0.5V to V_{DD} +0.5V
DC Output.....	-0.5V to V_{DD} +0.5V
DC Output Current (Q output).....	20mA

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

(GND=0V, unless otherwise noted.)

Sym.	Parameter	Conditions	MIN	TYP	MAX	Unit
V_{DD}	Supply voltage	-	1.6	-	5.5	V
T_A	Operating temperature	-	-45		+125	°C
f_0	Oscillation frequency ^{*1}	-	10		60	MHz



RSM

www.raystar-tek.com

XO5052Cx/Bx-Q
Fundamental Crystal Oscillator IC

DC Electrical Characteristics

XO5052(V_{DD} = 1.6 to 5.5V, T_A = -45 to 125°C, unless otherwise noted.)

Parameter	Sym	Conditions		MIN	TYP	MAX	Unit
HIGH-level output voltage	V_{OH}	$I_{OH}=1\text{mA}$	$V_{DD}-0.4$	-	-	-	V
LOW-level output voltage	V_{OL}		-	-	0.4	-	
HIGH-level input voltage	V_{IH}	OE Measurement	0.7Vcc	-	-	-	V
LOW-level input voltage	V_{IL}		OE Measurement	-	-	0.4	
Operating current	I_{CC}	$V_{DD}=1.8\text{V}(25\text{MHz})$, no loading	-	0.65	1.3	-	mA
Operating Current	I_{CC}	$V_{DD}=3.0\text{V}(25\text{MHz})$, no loading	-	1.4	2.8	-	mA
Operating Current	I_{CC}	$V_{DD}=1.8\text{V}(25\text{MHz}), 15\text{pf}$ loading	-	1.3	2.0	-	mA
Operating Current	I_{CC}	$V_{DD}=3.0\text{V}(25\text{MHz}), 15\text{pf}$ loading	-	2.5	3.5	-	mA
Standby Current	I_{SB}	OE=off				10	uA
OE pull-up resistance	R_{PULL}	$V_{DD} = 3.3\text{V}$		-	2	-	MΩ
Output leakage current	I_Z	OE=OFF	$V_O = V_{DD}$	-	-	10	μA

AC Characteristics

XO5052C/B, $T_A=-45$ to 125°C unless otherwise noted

Parameter	Symbol	Condition		MIN	TYP	MAX	Unit
Output Disable Delay	t_{OD}	Output Disable Function (OE)		-	-	100	ns
Output Enable Delay	t_{STR}	Output Enable Function (OE)		-	-	10	ms
Output rise time	t_{R1}	$C_L=15\text{pF}$, $0.1V_{DD}$ to $0.9V_{DD}$	$V_{DD}=3.3\text{V}$	-	1.6	2.5	ns
Output fall time	t_{F1}	$C_L=15\text{pF}$, $0.1V_{DD}$ to $0.9V_{DD}$	$V_{DD}=3.3\text{V}$	-	1.6	2.5	ns
Output duty cycle	Duty	$T_A=25^\circ\text{C}$, $C_L=15\text{pF}$		45	50	55	%
V_{DD} Sensitivity Frequency vs. $V_{DD}+/-10\%$		Frequency vs. $V_{DD}+/-10\%$		-1.5	-	+1.5	ppm
OSC frequency range	f_R	Fundamental Crystal		10		60	MHz

Crystal Specifications

Parameters	Sym	Conditions	MIN	TYP	MAX	Units
Fundamental Crystal Resonator Frequency(XO5052)	F_{XIN}	-	10		60	MHz
Maximum Sustainable Drive Level		-	-	-	200	μW
Operating Drive Level		-	-	30	-	μW
Crystal Shunt capacitance	C_0	-	-	-	4	pF
Effective Series Resistance, Fundamental, 10-60MHz	ESR	-	-	-	40	Ω



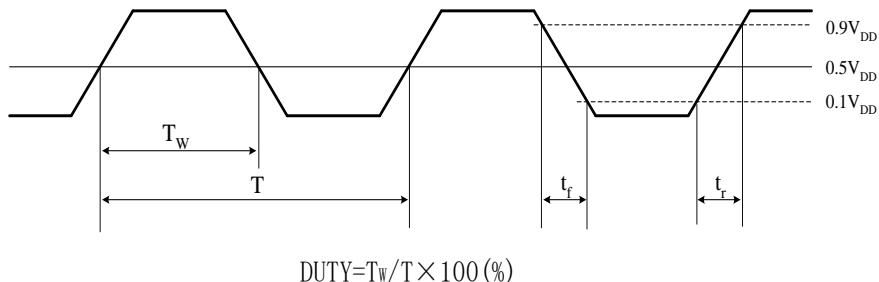
RSM

www.raystar-tek.com

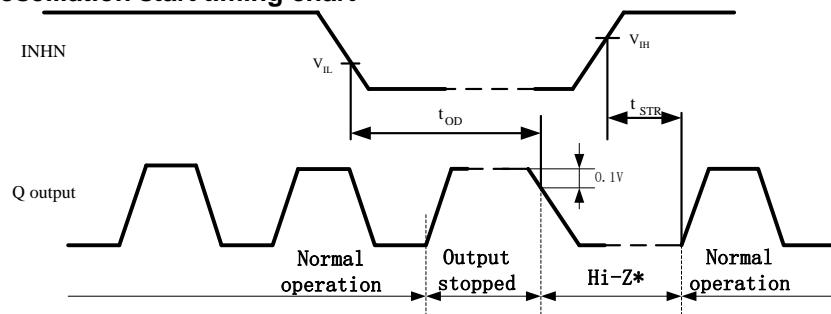
XO5052Cx/Bx-Q
Fundamental Crystal Oscillator IC

AC Electrical Characteristics

Output switching waveform



Output disable and oscillation start timing chart



When INHN goes HIGH to LOW, the Q output goes HIGH once and then becomes high impedance.

When INHN goes LOW to HIGH, the Q output from high impedance to normal output operation when the oscillation starts (oscillation is detected)

*: the high -impedance interval in the figure is shown as a LOW level due to the 1KΩ pull-down resistor connected to the Q pin(see“Measurement circuit 2”in the “Measurement circuits” section)



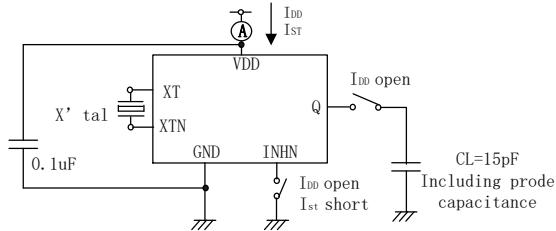
RSM

www.raystar-tek.com

XO5052Cx/Bx-Q
Fundamental Crystal Oscillator IC

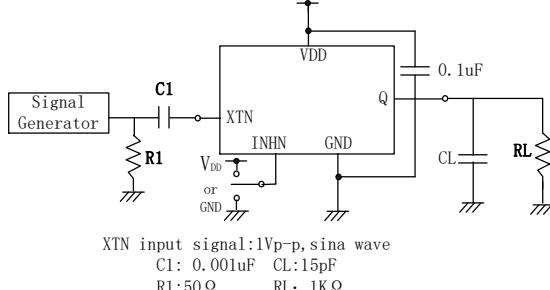
Measurement Circuit

Measurement cct1

Measurement parameter: I_{DD} , I_{ST} , Duty, t_r , t_f 

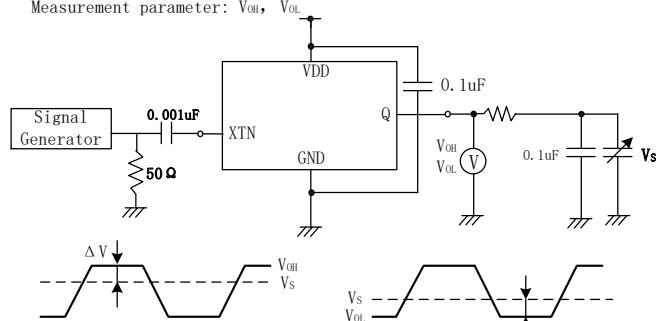
Note: The AC characteristics are observed using an oscilloscope on pin Q

Measurement cct2

Measurement parameter: t_{DD} 

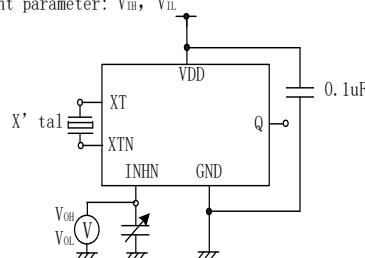
XTN input signal: 1Vp-p, sines wave
 $C_1: 0.001\mu F$ $C_L: 15pF$
 $R_1: 50\Omega$ $R_L: 1K\Omega$

Measurement cct3

Measurement parameter: V_{OH} , V_{OL} Vs adjusted such that $\Delta V = 50 \times I_{OH}$ Vs adjusted such that $\Delta V = 50 \times I_{OL}$

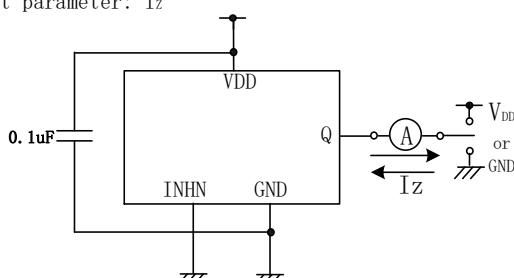
XTN input signal: 1Vp-p, sines wave

Measurement cct4

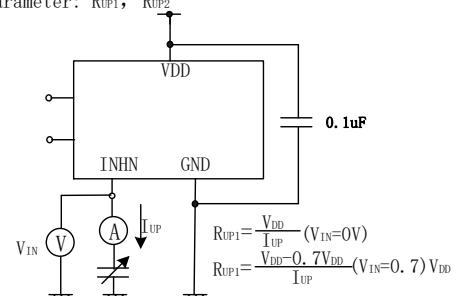
Measurement parameter: V_{IH} , V_{IL} 

V_{IH} : Voltage is 0V to V_{DD} transition that changes the output state.
 V_{IL} : Voltage is V_{DD} to 0V transition that changes the output state.
INHN has an oscillation stop function

Measurement cct5

Measurement parameter: I_Z 

Measurement cct6

Measurement parameter: R_{UP1} , R_{UP2} 

$$R_{UP1} = \frac{V_{DD}}{I_{UP}} \quad (V_{IN}=0V)$$

$$R_{UP1} = \frac{V_{DD}-0.7V_{DD}}{I_{UP}} \quad (V_{IN}=0.7V_{DD})$$



RSM

www.raystar-tek.com

XO5052Cx/Bx-Q
Fundamental Crystal Oscillator IC

Revision History

Revision	Description	Date
V1.0	Official release	2023/7/11
V1.1	Updated part name from XO5052xy-Q-zWF/ XO5052xy-Q-zDE to XO5052xy-zWF-Q/ XO5052xy-zDE-Q	2024/1/5